

Layout



- Thermionic
- Photo-Cathodes
- Child-Langmuir Current Limitation

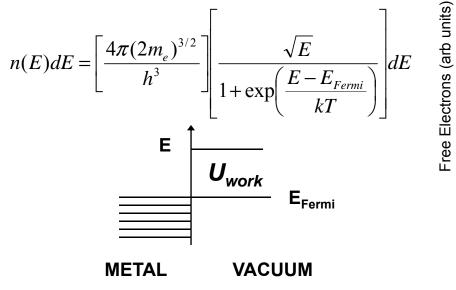
Ion Sources

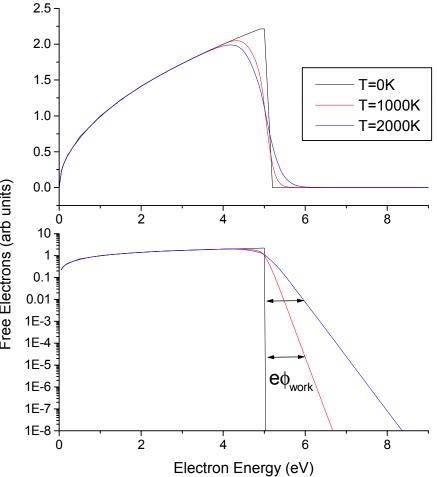
- Penning Ion Source
- ECR Ion Source
- Negative lons



Electrons – Thermionic Emission

When a material is heated, the electrons energy distribution shifts from the zero temperature Fermi distribution.







Electrons – Thermionic Emission

 Therefore at high temperatures there is an ELECTRON CLOUD around the material. The current density can then be found by integrating the available electrons and their energy.

$$J = A \cdot T^2 \exp\left(\frac{-eU_{work}}{kT}\right)$$

$$A = \frac{4\pi e m_e k^2}{h^3} \approx 1.2 \times 10^6 \,\mathrm{Am}^{-2} K^{-1}$$

This electron current is available to be pulled off the surface... Richardson-Dushmann equation *Rev. Mod. Phys. 2, p382 (1930)*

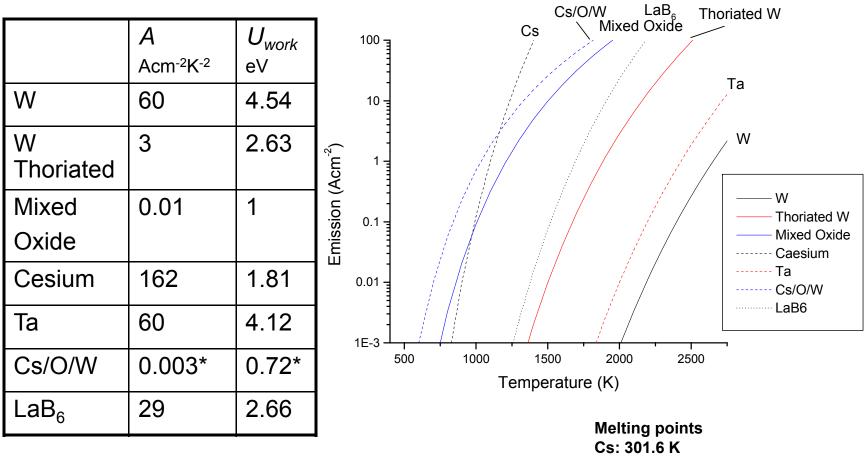
⁻² This factor **A** is not achieved In practice.

 The current density is further increased by the Schottky effect – the electric field on the surface, used to extract the electrons, allows electron tunneling
 Where F is in kV/cm => 15%

$$J = J_{R-D} \times \exp\left(\frac{139E_s}{T}\right) \qquad \text{for 1kV/cm @1000K} \qquad E_{\text{Fermi}} \qquad U_{work} \qquad \text{METAL} \qquad \text{VACUUM}$$



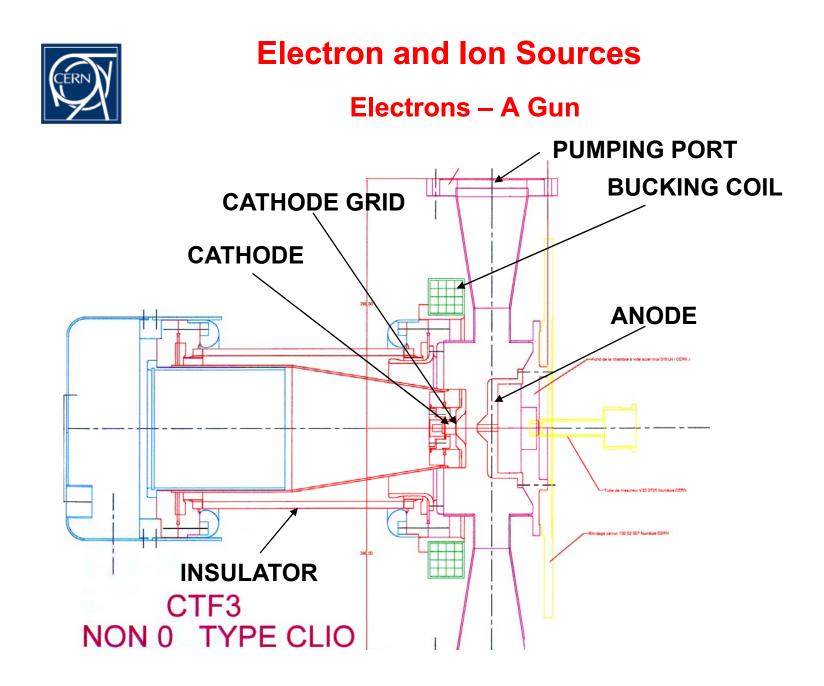
Electrons – Thermionic Emission



*- A and work function depend on the Cs/O layer

Thickness and purity

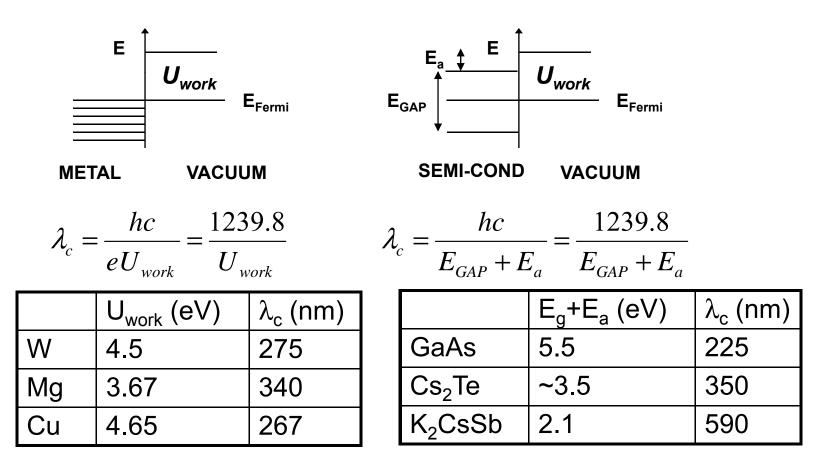
Ta: 3290 K W: 3695 K LaB₆: ~2800 K (decomp)





Electrons – Photo Emission

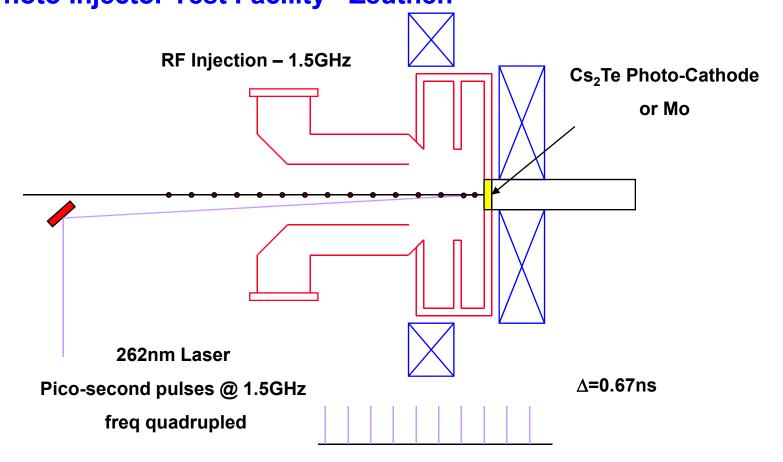
- The energy of an electron in a material can be increased above the vacuum energy by absorbing photons photoelectric effect.
- Photocathode





Electrons – Photo Injector

 Photo cathodes can produce bunch structure of the same length as the light pulse.
 Photo Injector Test Facility - Zeuthen





Electrons – Photo Cathodes

• Quantum Efficiency = Electrons/photon [$Q_e(\lambda)$]

GaAs:Cs=17%, CsTe=12.4%, K2CsSb=29%, Cu~0.01%,

METALS

- If desired, can be almost-"blind" to optical or infra-red.
- Using the thermal electrons above the Fermi Energy, can make a very low current source using optical wavelengths.
- At high optical powers, a plasma is formed.

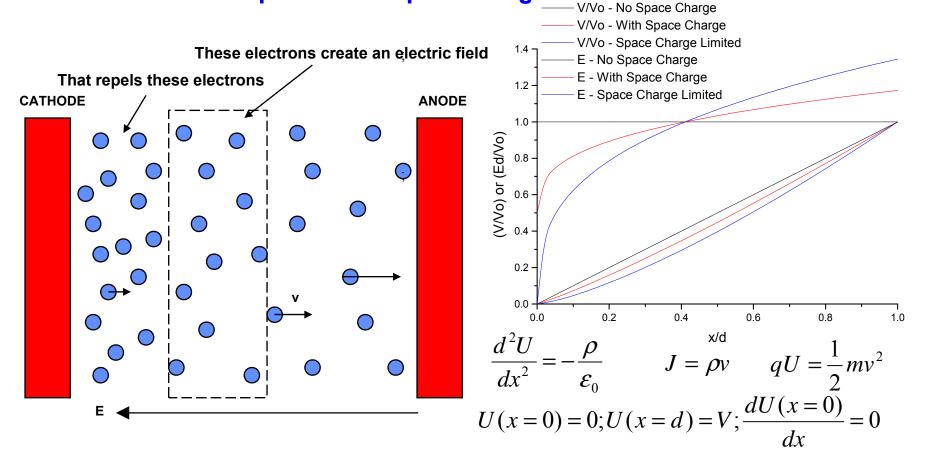
SEMICONDUCTORS

- Can find materials optical wavelengths with high quantum efficiency (cf Photo Cathode Tubes).
- Difficult to use in a high radiation area of an electron-gun (xrays and ions cause decomposition and surface damage).
- Common material=Cs₂Te (Cesium Telluride)– High Quantum efficiency & stable.



Electrons – Child-Langmuir Law

- Child-Langmuir law (3/2 power law) gives the limit of current that can be removed from a surface.
- Need electric field to remove electrons from surface.
- Electrons set up their own space charge field.



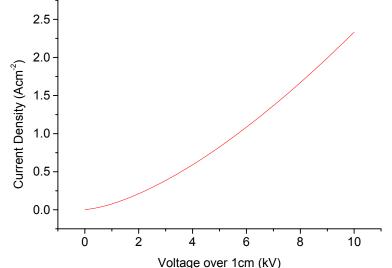


Electrons – Child-Langmuir Law

 Hence there is a MAXIMUM current density that can be extracted for a given voltage and gap.

$$J_{C-L} = \frac{4}{9} \varepsilon_0 \left(\frac{2q}{m}\right)^{1/2} \frac{V^{3/2}}{d^2}$$

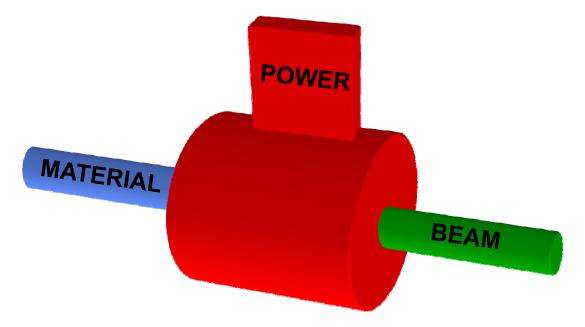
- d : Cathode to Anode distance
 V : Cathode to Anode voltage
 q : particle charge
 m : particle mass
 This is not relativistic
- If the cathode-anode voltage is varied, so is the electrode current.
- If the cathode-anode voltage is ZERO, no current is extracted -> Cathode Grid.





Ion Sources - Basics

- An Ion Source requires an "ion production" region and an "ion extraction" system.
- In most (but not all) cases, ion production occurs in a plasma.



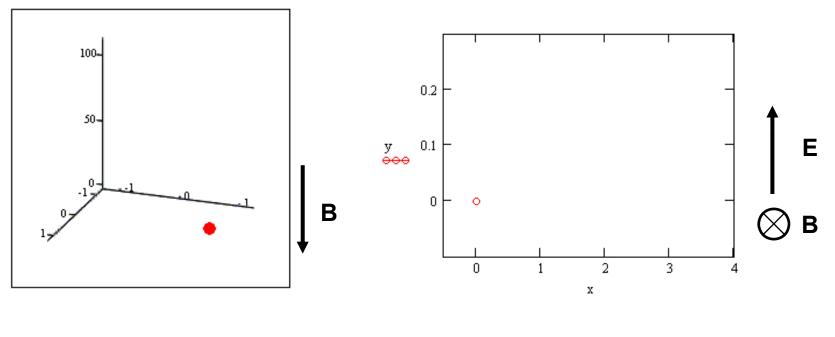


Ion Sources - Basics

- Plasma Processes
 - Electron heating
 - Plasma confinement (electric and magnetic)
 - Collisions (e-e, e-i, i-e, i-i + residual gas)
 - Atomic processes (ionisation, excitation, disassociation, recombination)
 - Surface physics (coatings + desorbtion, e-emission)
 - Mechanical processes (chamber heating+cooling, erosion)
- Ion Source Goal -> Optimise these processes to produce the required ion type and pulse parameters.
- AND maximize reliability, minimize emittance, power and material consumption.



Plasma Particle Motion



$$\rho_L = \frac{\sqrt{2mE_\perp}}{eB}, \omega_L = \frac{eB}{m}$$

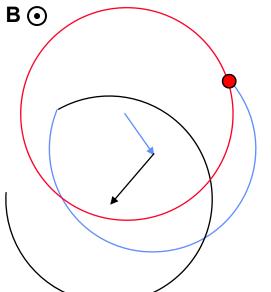
$$v_{drift} = \frac{\vec{E} \times \vec{B}}{B^2}$$



Plasma Particle Motion

$$D \sim \rho_L^2 v_c \sim \left(\frac{\sqrt{2m_p E_\perp}}{eB}\right)^2 \frac{1}{T^{3/2}} \left(\frac{m_e}{m_p}\right)^{1/2} \sim \frac{m_p^{1/2}}{T^{1/2}}$$

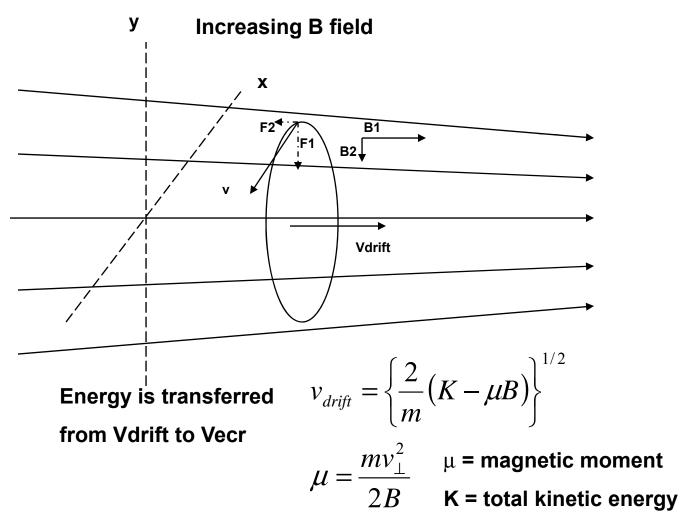
cf: opposite to classical
energy – velocity equation !
$$v = \left(\frac{2E}{m}\right)^{1/2}$$





ECR Source – Magnetic Mirror

A force acts in the opposite direction to the

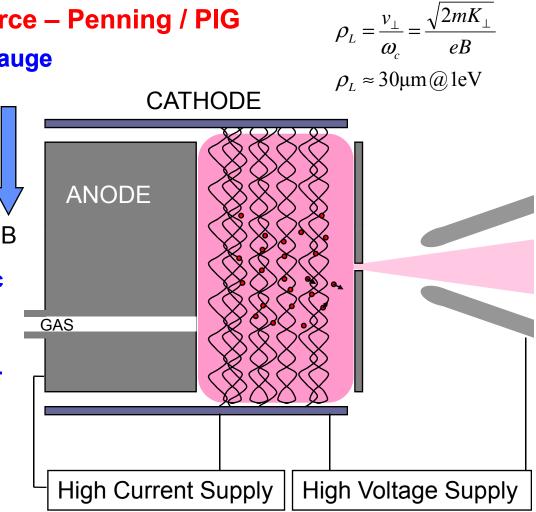


Ion Source – Penning / PIG

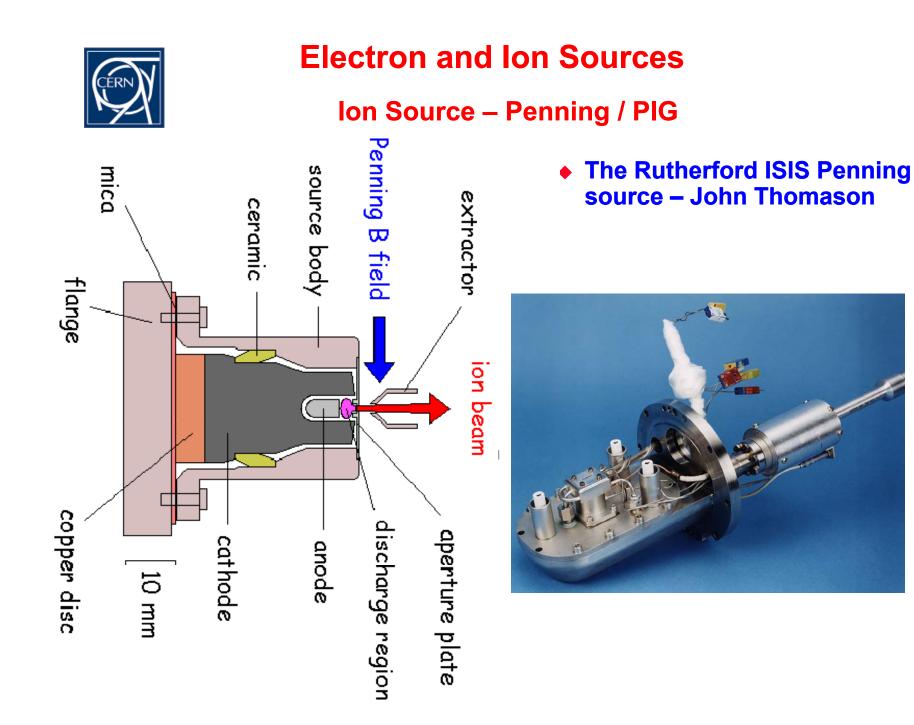
Penning or Philips Ionisation Gauge (PIG) source

Gas Pressure 10⁻³ -> 1 mbar Arc Voltage ~1kV Arc Current 0.1 -> 50 A Magnetic Field >0.1T

- Cathode can be Hot or Cold
- Electrons are accelerated by the arc voltage across the cathode sheath layer.
- Magnetic field stops cathode electrons reaching the anode (>0.1T required).
- Some electrons strike the anticathode.
- Otherwise they may oscillate in the Penning Trap and ionise the gas.
- **Electrons go to the anode by** diffusion processes, plasma oscillations and the plasma-anode potential.









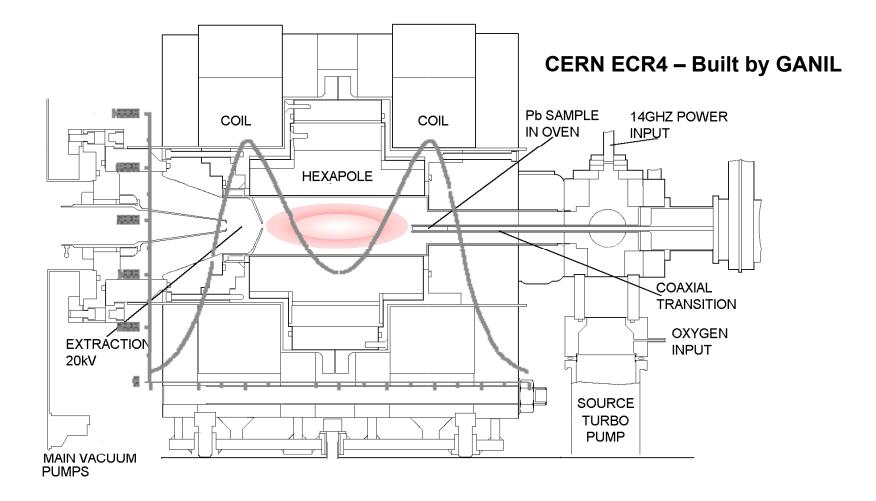
Ion Source – ECR

- Electron Cyclotron Resonance Ion Source (ECR)
- For a given magnetic field, nonrelativistic electrons have a fixed revolution frequency.
- The plasma electrons will absorb energy at this frequency.
- If confined in a magnetic bottle, the electrons can be heated to the keV and even MeV range.
- Ions also trapped by the charge of the electrons, but for milli-seconds allowing mutliple ionisation.
- The solenoid magnetic field still allows losses on axis – these ions make the beam.

$$\omega_{ecr} = \frac{eB}{m}$$
$$f_{ce}[GHz] = 2.8 \times B[kG]$$



Ion Source – ECR





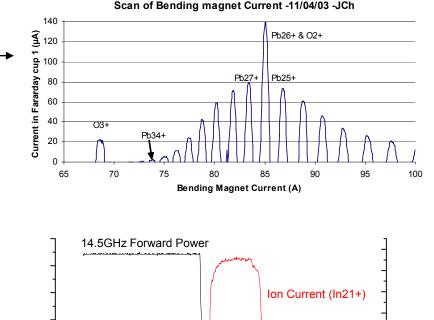
Ion Source – ECR

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- No filament is needed, greatly increasing the source lifetime.
- Singly, multiply and highly charged ions can be produced by these sources (although the source construction will influence this).
 A → A+ → A2+ → A3+

Stepwise ionisation.

- Gaseous ions are easily made. Metallic ions come from an OVEN or from a compound gas (e.g UF6 for uranium).
- In the afterglow mode, the ion intensity increases AFTER switching off the micro-waves.



2

3

Time (ms)

5



Ion Sources – Negative Ions

 Negative ion sources allow charge exchange injection into synchrotrons.

	Electron Affinity (eV)
Н	0.7542
He	<0
Li	0.6182
Be	<0
В	0.277
С	1.2629
Ν	<0
0	1.462
F	3.399

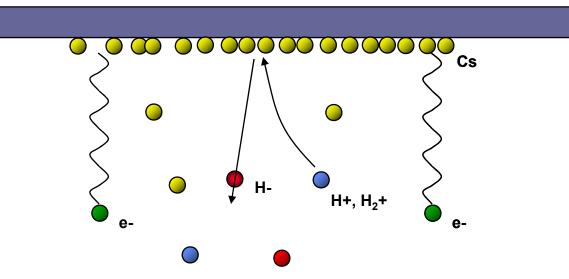
- The bonding energy for an electron onto an atom is the Electron Affinity.
- Ea < 0 for Noble Gasses
- Large Ea for Halogens
- Two categories of negative ion sources
 - Surface an atom on a surface can be desorbed with an extra electron (whose wave-function overlapped the atom).
 - Volume Through collisions, e-capture and molecular dissociation, negative ions can be formed.

 $AB + e \rightarrow A - + B$ $A + B \rightarrow A - + B +$ $AB^* + e \rightarrow A - + B$ $A + + B \rightarrow A - + B2 +$

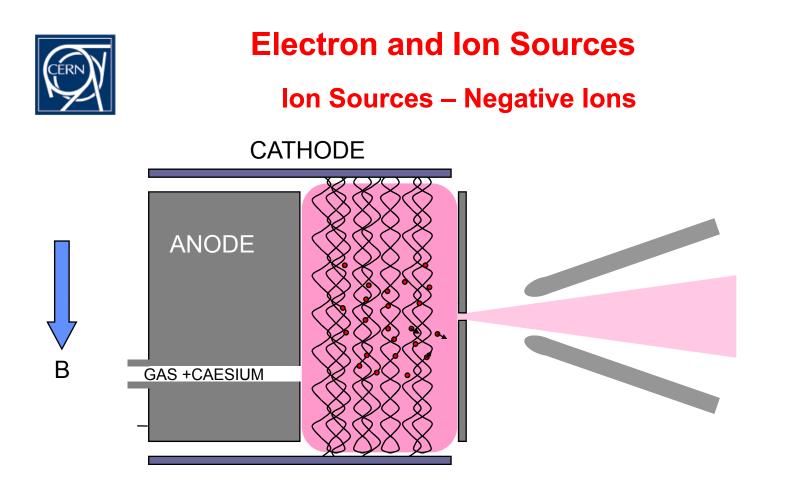


H- Surface Ion Production

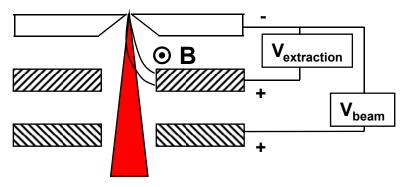
CATHODE



- Protons from the plasma are accelerated to the cathode, which has a coating of caesium.
- The protons desorbed from the low work function surface, with an additional electron.
- The plasma must not be too hot, to avoid ionising the H-.
- Penning, Magnetron, etc, sources produce H this way.



• Electrons are extracted along with negative ions! Electron current can be reduced with a dipole B field in extraction.





Summary

Electron Source Summary

- Thermionic Source. Some thermal electrons are above the Work-Function.
- Use low work-function or high melting point materials to obtain the most electrons
- Photo-cathodes Use photons above the work-function or E_g+E_a.
- Metals Stable but have a low quantum efficiency
- Semiconductors high Q, but can be unstable and degrade in use.
- Require an field to extract electrons $J \sim V^{3/2} / d^2$.

Ion Source Summary

- A vast array of ion source type. Using surfaces, sputtering, plasmas and different heating configurations.
- PIG/Penning Cathode-Anode discharge in a magnetic field, where electrons oscillate in a plasma, ionizing the rest gas.
- ECR Heating of electrons on the ECR resonance, producing a plasma. Electrons and ions are confined in a magnetic bottle. Confinement leads to multiple collisions and highly charged-ions.
- Negative ions of elements with a high electron affinity can be produced.
 H- requires a warm plasma to excite H2. In a cooler plasma region, electron attachment and disassociation occurs.



Further Reading

- Handbook of Ion Source, B. Wolf, Boca Raton, FL: CRC Press, 1995
- Ion Sources, Zhang Hua Shun, Berlin: Springer, 1999.
- The Physics and Technology of Ion Source, I. G. Brown, New York, NY: Wiley, 1989
- Large Ion Beams: Fundamentals of Generation and Propagation, T. A .Forrester, New York, NY: Wiley, 1988
- CAS 5th General School (CERN 94-01) and Cyclotrons, Linacs... (CERN-96-02)